

DESCRIPTION

The MGFC36VXXXX products are internally impedance matched devices for use in C-band power amplifier applications.

This family of devices uses high performance source island via-hole GaAs die which offer excellent electrical and thermal resistance characteristics.

These devices are available screened for IM₃ performance by specifying '-51' as the part number suffix. (See ordering information at the back of this product data sheet.)

FEATURES

- Class A operation
- Internally matched to 50Ω
- High output power
- High linearity
- High power gain
- High power added efficiency
- Hermetically sealed metal-ceramic package

FREQUENCIES

TYPE	FREQUENCY
MGFC36V3742	3.7 – 4.2 GHz
MGFC36V4450	4.4 – 5.0 GHz
MGFC36V5258	5.2 – 5.8 GHz
MGFC36V5964	5.9 – 6.4 GHz
MGFC36V6471	6.4 – 7.1 GHz
MGFC36V7177	7.1 – 7.7 GHz
MGFC36V7785	7.7 – 8.5 GHz

ABSOLUTE MAXIMUM RATINGS (T_a = 25°C)

SYMBOL	PARAMETER	RATINGS	UNIT
V _{GDO}	Gate to drain voltage	-15	V
V _{GSO}	Gate to source voltage	-15	V
I _D	Drain current	2.8	A
I _{GR}	Gate current (reverse)	-10	mA
I _{GF}	Gate current (forward)	+21	mA
P _T	Total power dissipation*1	25	W
T _{ch}	Channel temperature	175	°C
T _{stg}	Storage temperature	-65 – +175	°C
R _{th (ch-a)}	Thermal resistance*2	6	°C/W

*1. T_C = 25°C

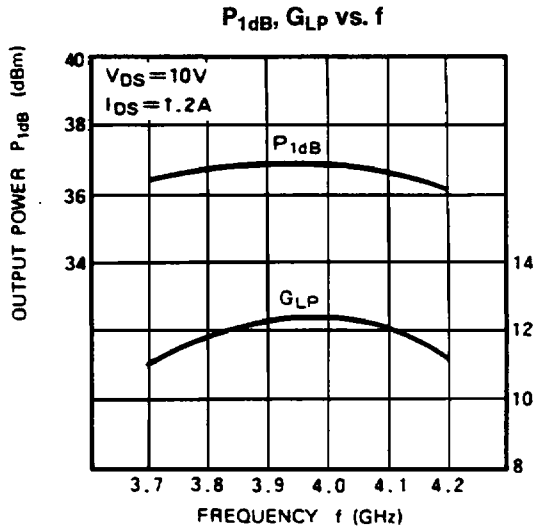
*2. Channel to case

ELECTRICAL CHARACTERISTICS ($T_a = 25^\circ\text{C}$)

SYMBOL	PARAMETER	TEST CONDITIONS	TYPE	LIMITS			UNIT	
				MIN	TYP	MAX		
I_{DSS}	Saturated drain current	$V_{DS} = 3V, V_{GS} = 0V$		—	2.0	2.8	A	
g_m	Transconductance	$V_{DS} = 3V, V_{GS} = 0/-1V$		—	1.0	—	S	
$V_{GS(off)}$	Gate to source cut-off voltage	$V_{DS} = 3V, I_D = 80mA$		-2	-3	-4	V	
P_{1dB}	Output power at 1dB gain compression	$V_{DS} = 10V, I_{DS} = 1.2A$		35	36	—	dBm	
IM_3	Third order intermodulation distortion	$V_{DS} = 10V, I_{DS} = 1.2A$ 2 tones, +25dBm S.C.L.; $\Delta F = 10MHz$	*-51* selection		-45	-42	dBc	
G_{LP}	Linear power gain	$V_{DS} = 10V$ $I_D = 1.2A$	f = 3.7 ~ 4.2 GHz	MGFC36V3742	10	11	—	dB
			f = 4.4 ~ 5.0 GHz	MGFC36V4450	9	10	—	
			f = 5.2 ~ 5.8 GHz	MGFC36V5258	9	10	—	
			f = 5.9 ~ 6.4 GHz	MGFC36V5964	9	10	—	
			f = 6.4 ~ 7.1 GHz	MGFC36V6471	8	9	—	
η_{add}	Power added efficiency		f = 7.1 ~ 7.7 GHz	MGFC36V7177	8	9	—	%
			f = 7.7 ~ 8.5 GHz	MGFC36V7785	7	8	—	
			f = 3.7 ~ 4.2 GHz	MGFC36V3742	—	33	—	
			f = 4.4 ~ 5.0 GHz	MGFC36V4450	—	32	—	
			f = 5.2 ~ 5.8 GHz	MGFC36V5258	—	32	—	
R_g	Gate resistance	f = 5.9 ~ 6.4 GHz	MGFC36V5964	—	32	—		
		f = 6.4 ~ 7.1 GHz	MGFC36V6471	—	30	—		
		f = 7.1 ~ 7.7 GHz	MGFC36V7177	—	30	—		
		f = 7.7 ~ 8.5 GHz	MGFC36V7785	—	29	—		
				—	100	—	Ω	

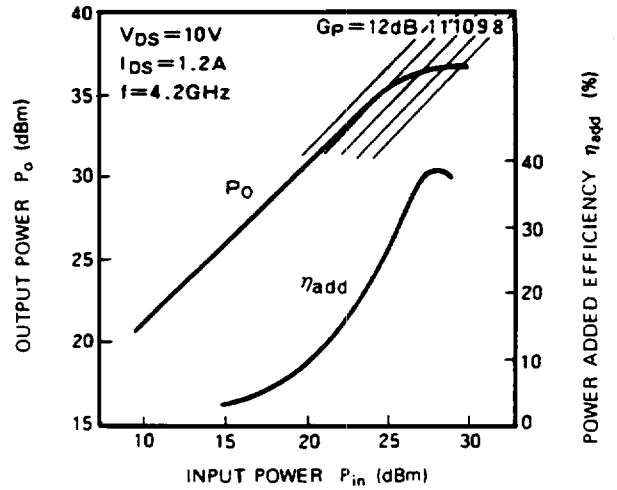
TYPICAL CHARACTERISTICS ($T_a = 25^\circ\text{C}$)

MGFC36V3742



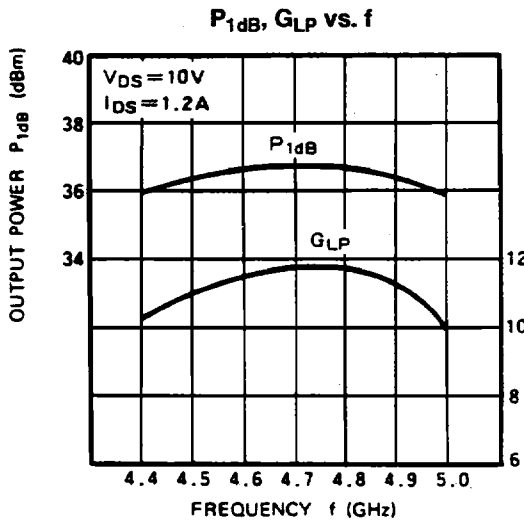
LINEAR POWER GAIN G_{LP} (dB)

P_O , η_{add} vs. P_{IN}



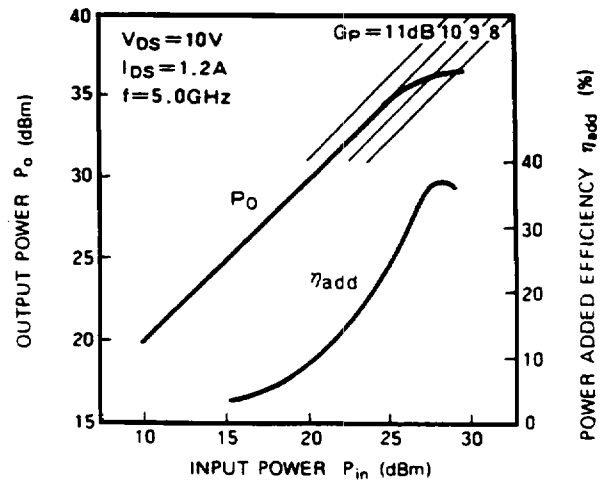
POWER ADDED EFFICIENCY η_{add} (%)

MGFC36V4450



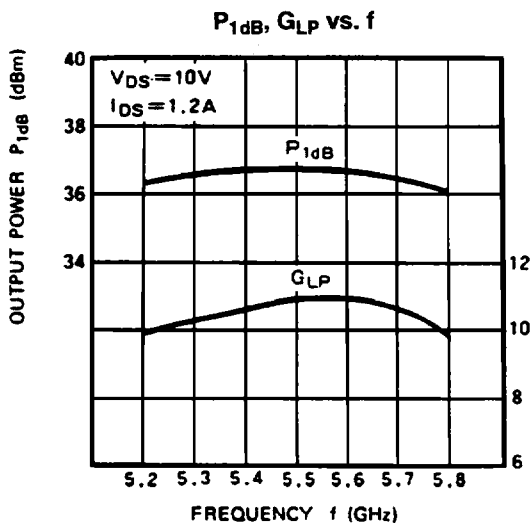
LINEAR POWER GAIN G_{LP} (dB)

P_O , η_{add} vs. P_{IN}



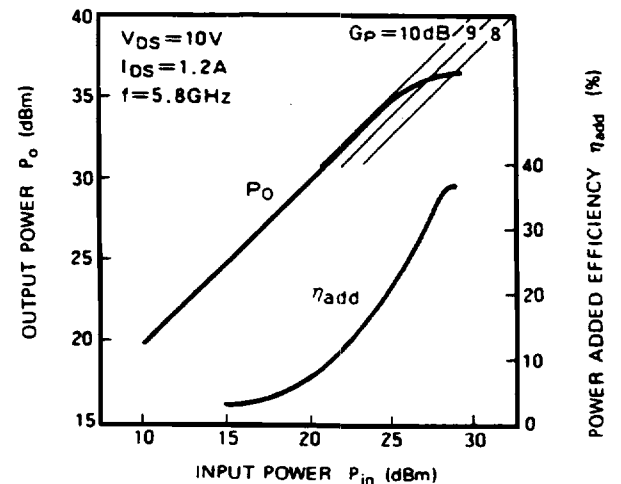
POWER ADDED EFFICIENCY η_{add} (%)

MGFC36V5258



LINEAR POWER GAIN G_{LP} (dB)

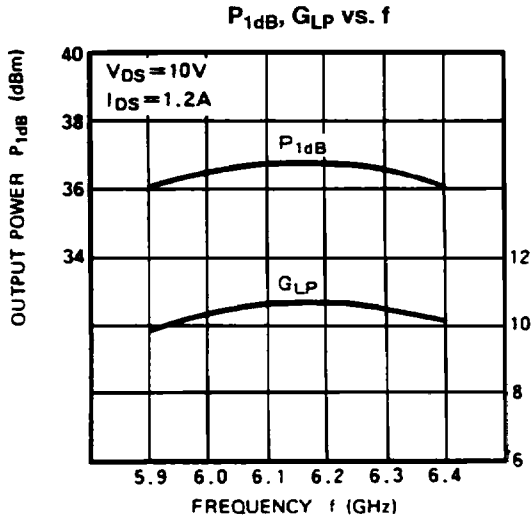
P_O , η_{add} vs. P_{IN}



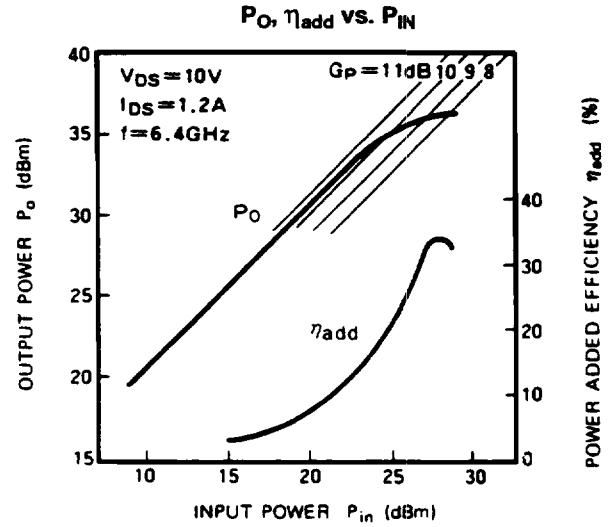
POWER ADDED EFFICIENCY η_{add} (%)

TYPICAL CHARACTERISTICS ($T_a = 25^\circ\text{C}$)

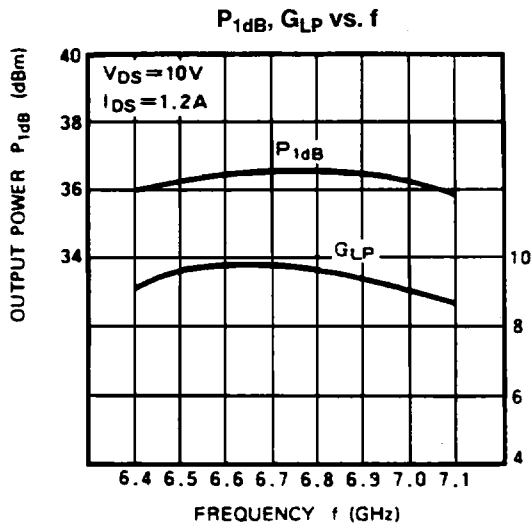
MGFC36V5964



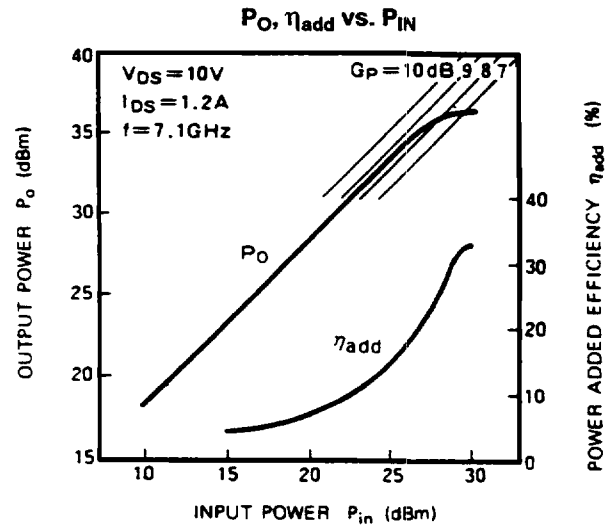
LINEAR POWER GAIN G_{LP} (dB)



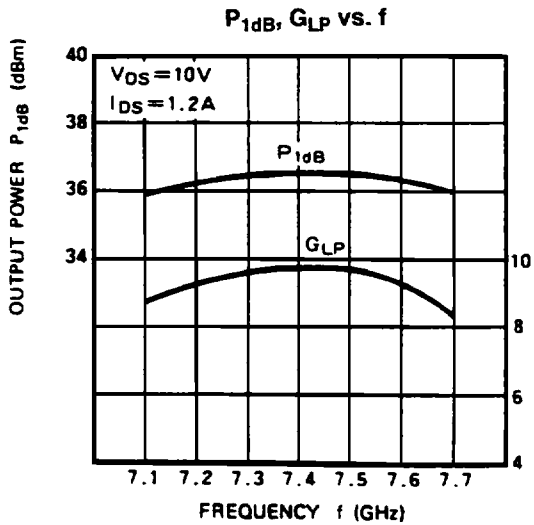
MGFC36V6471



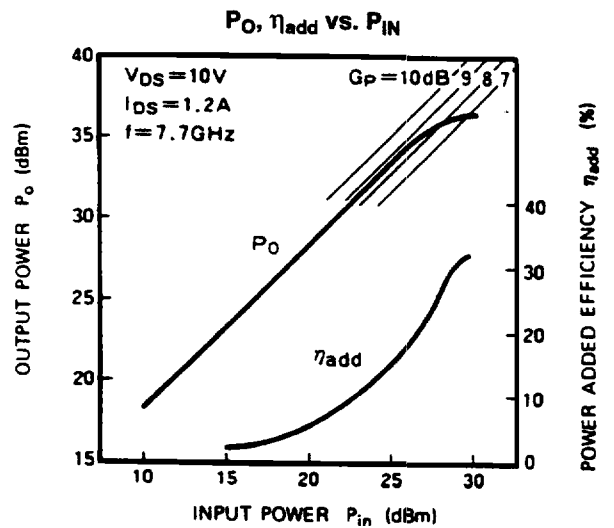
LINEAR POWER GAIN G_{LP} (dB)



MGFC36V7177

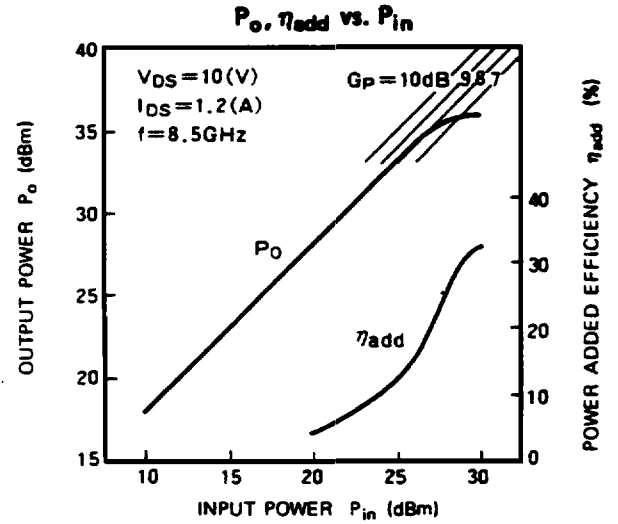
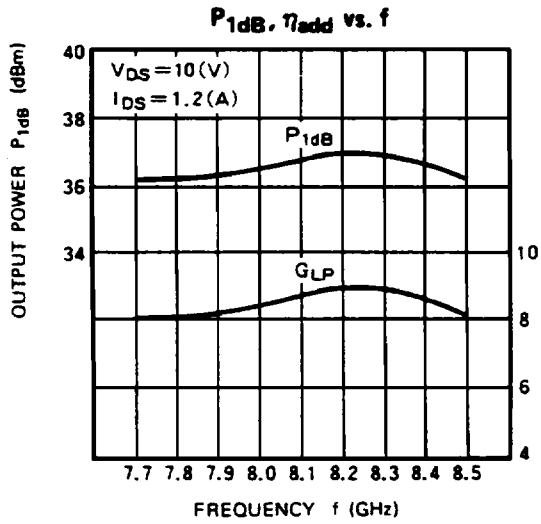


LINEAR POWER GAIN G_{LP} (dB)

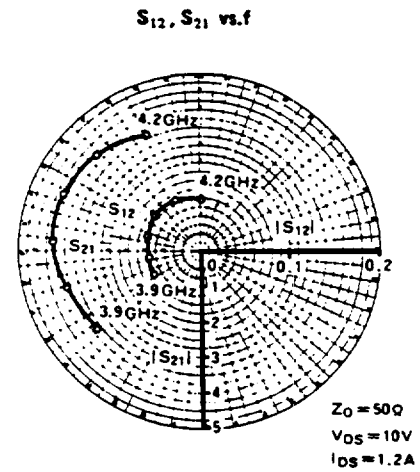
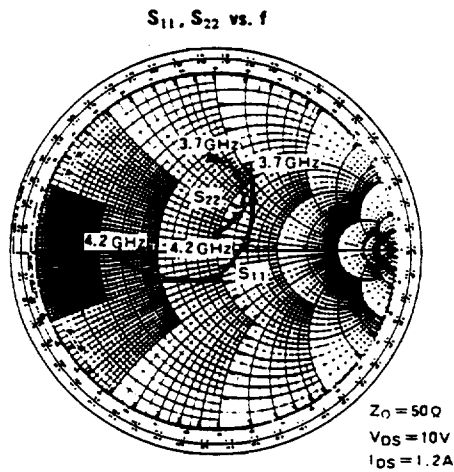


TYPICAL CHARACTERISTICS ($T_a = 25^\circ\text{C}$)

MGFC36V7785



MGFC36V3742

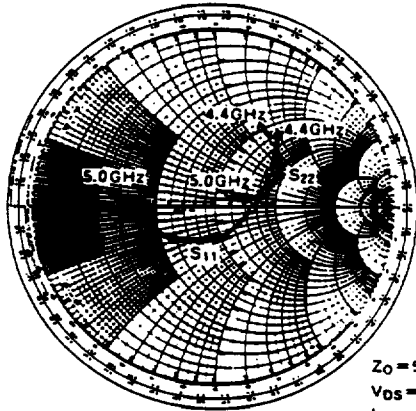


S PARAMETERS ($T_a = 25^\circ\text{C}$, $V_{DS} = 10\text{ V}$, $I_{DS} = 1.2\text{ A}$)

f (GHz)	S Parameters (TYP.)							
	S_{11}		S_{12}		S_{21}		S_{22}	
	Magn	Angle (deg.)	Magn	Angle (deg.)	Magn	Angle (deg.)	Magn	Angle (deg.)
3.7	0.51	69	0.058	-151	3.60	-143	0.53	92
3.8	0.36	54	0.058	-172	3.85	-164	0.50	83
3.9	0.17	20	0.060	165	4.04	178	0.46	74
4.0	0.15	-92	0.062	140	4.06	157	0.38	64
4.1	0.35	-155	0.061	114	3.98	136	0.24	58
4.2	0.58	-177	0.059	89	3.63	114	0.11	85

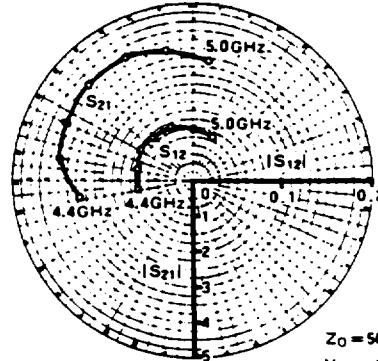
MGFC36V4450

S₁₁, S₂₂ vs. f



Z₀ = 50Ω
V_{DS} = 10V
I_{DS} = 1.2A

S₁₂, S₂₁ vs. f



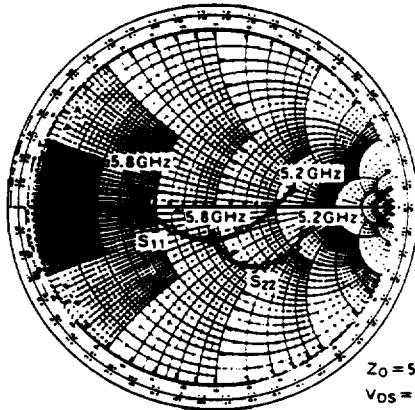
Z₀ = 50Ω
V_{DS} = 10V
I_{DS} = 1.2A

S PARAMETERS (T_a = 25°C, V_{DS} = 10V, I_{DS} = 1.2A)

f (GHz)	S Parameters (TYP.)							
	S ₁₁		S ₁₂		S ₂₁		S ₂₂	
	Magn.	Angle (deg.)	Magn.	Angle (deg.)	Magn.	Angle (deg.)	Magn.	Angle (deg.)
4.4	0.53	49	0.061	-171	3.19	-171	0.52	59
4.5	0.32	32	0.061	170	3.71	171	0.50	49
4.6	0.19	-2	0.063	151	3.80	155	0.45	38
4.7	0.17	-88	0.064	132	3.89	137	0.39	28
4.8	0.31	-142	0.064	111	3.85	118	0.28	19
4.9	0.45	-171	0.059	89	3.73	101	0.17	15
5.0	0.59	173	0.056	66	3.40	82	0.11	42

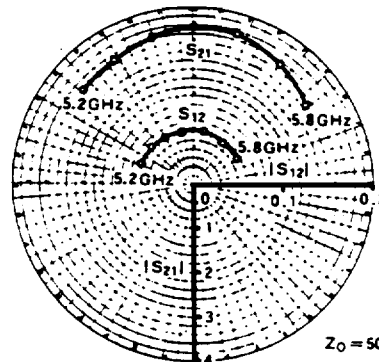
MGFC36V5258

S₁₁, S₂₂ vs. f



Z₀ = 50Ω
V_{DS} = 10V
I_{DS} = 1.2A

S₁₂, S₂₁ vs. f

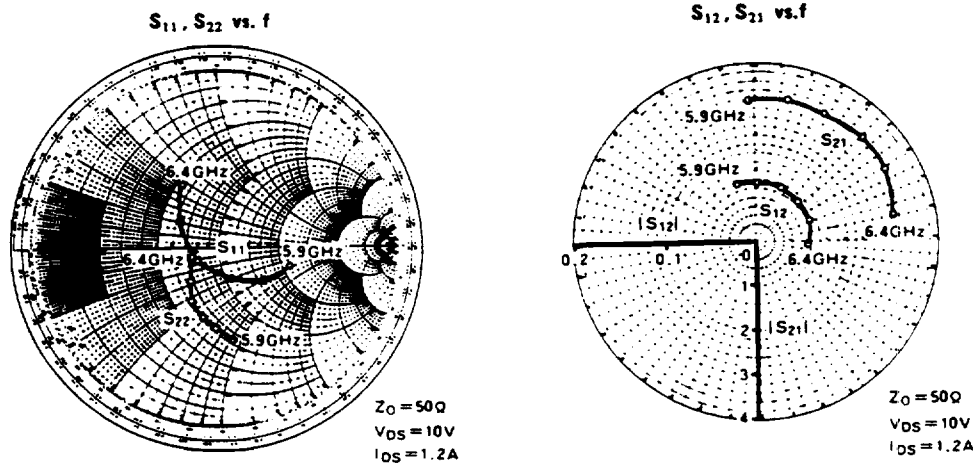


Z₀ = 50Ω
V_{DS} = 10V
I_{DS} = 1.2A

S PARAMETERS (T_a = 25°C, V_{DS} = 10V, I_{DS} = 1.2A)

f (GHz)	S Parameters (TYP.)							
	S ₁₁		S ₁₂		S ₂₁		S ₂₂	
	Magn.	Angle (deg.)	Magn.	Angle (deg.)	Magn.	Angle (deg.)	Magn.	Angle (deg.)
5.2	0.43	13	0.062	156	3.27	138	0.51	-17
5.3	0.30	-3	0.062	138	3.30	122	0.48	-28
5.4	0.19	-41	0.062	120	3.45	105	0.46	-39
5.5	0.18	-99	0.060	102	3.61	89	0.41	-51
5.6	0.28	-152	0.061	78	3.61	73	0.34	-66
5.7	0.39	179	0.059	56	3.45	55	0.26	-80
5.8	0.51	161	0.058	32	3.19	36	0.17	-98

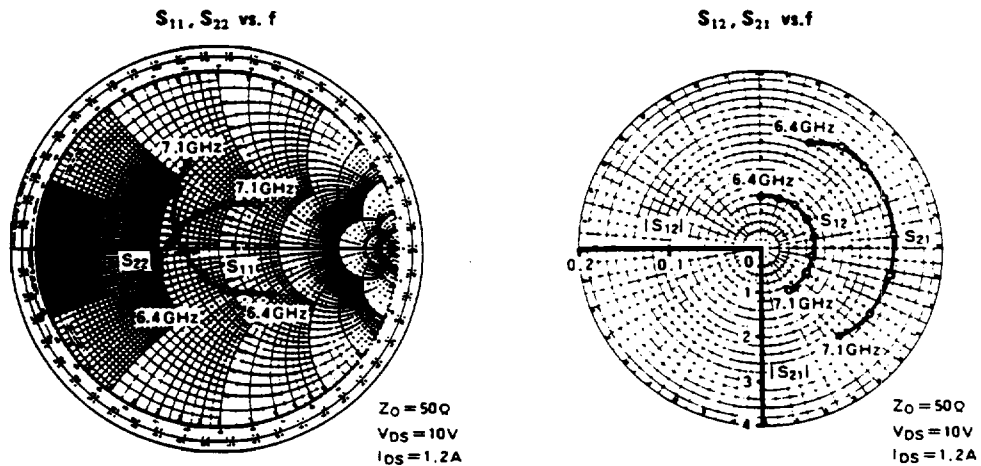
MGFC36V5964



S PARAMETERS ($T_a = 25^\circ\text{C}$, $V_{DS} = 10\text{V}$, $I_{DS} = 1.2\text{A}$)

f (GHz)	S Parameters (TYP.)							
	S ₁₁		S ₁₂		S ₂₁		S ₂₂	
	Magn.	Angle (deg.)	Magn.	Angle (deg.)	Magn.	Angle (deg.)	Magn.	Angle (deg.)
5.9	0.41	-16	0.068	110	3.20	93	0.52	-83
6.0	0.26	-39	0.068	88	3.31	76	0.46	-94
6.1	0.19	-73	0.067	65	3.30	61	0.42	-104
6.2	0.16	-151	0.066	44	3.35	44	0.34	-118
6.3	0.25	146	0.063	21	3.30	29	0.25	-130
6.4	0.40	118	0.059	-2	3.16	12	0.16	-159

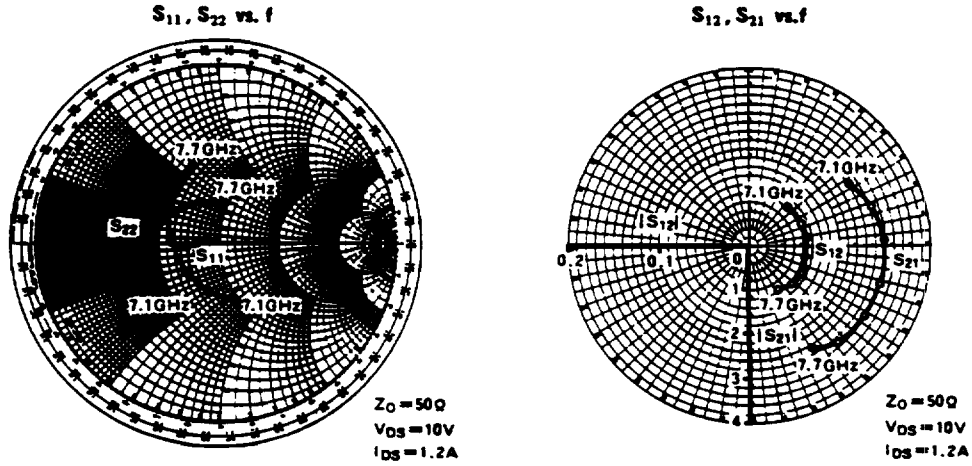
MGFC36V6471



S PARAMETERS ($T_a = 25^\circ\text{C}$, $V_{DS} = 10\text{V}$, $I_{DS} = 1.2\text{A}$)

f (GHz)	S Parameters (TYP.)							
	S ₁₁		S ₁₂		S ₂₁		S ₂₂	
	Magn.	Angle (deg.)	Magn.	Angle (deg.)	Magn.	Angle (deg.)	Magn.	Angle (deg.)
6.4	0.38	-41	0.058	87	2.70	64	0.42	-135
6.5	0.31	-55	0.060	69	2.99	51	0.38	-146
6.6	0.23	-81	0.064	52	3.05	38	0.34	-158
6.7	0.17	-119	0.064	34	3.00	22	0.29	-179
6.8	0.19	-174	0.062	13	3.05	6	0.25	151
6.9	0.26	153	0.060	-9	2.95	-11	0.23	117
7.0	0.39	124	0.059	-30	2.85	-31	0.26	78
7.1	0.52	108	0.056	-52	2.60	-48	0.33	49

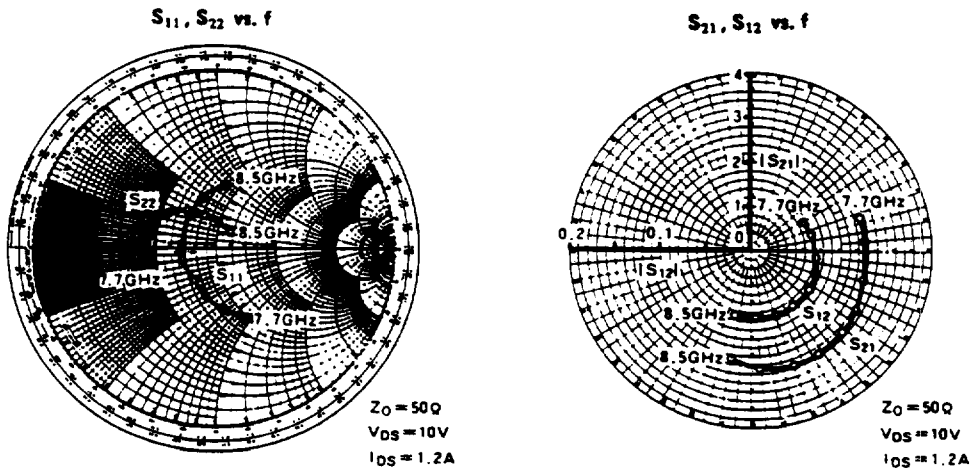
MGFC36V7177



S PARAMETERS ($T_a = 25^\circ\text{C}$, $V_{DS} = 10\text{V}$, $I_{DS} = 1.2\text{A}$)

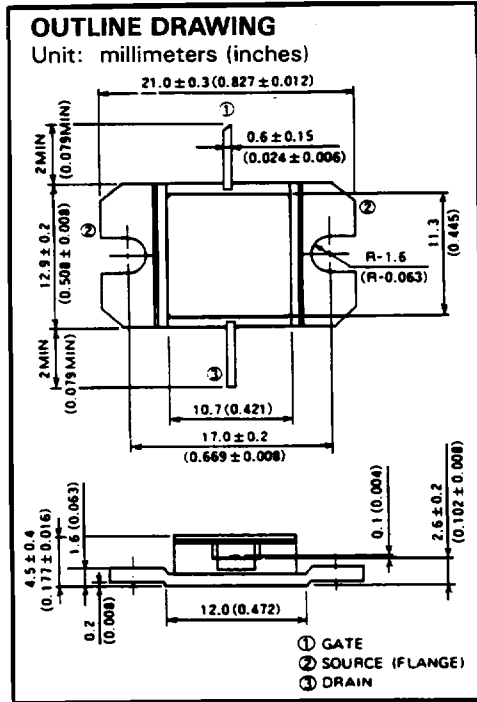
f (GHz)	S Parameters (TYP.)							
	S ₁₁		S ₁₂		S ₂₁		S ₂₂	
	Magn.	Angle (deg.)	Magn.	Angle (deg.)	Magn.	Angle (deg.)	Magn.	Angle (deg.)
7.1	0.34	-77	0.061	42	2.65	32	0.46	-145
7.2	0.28	-105	0.062	24	2.87	17	0.41	-161
7.3	0.25	-139	0.064	8	3.02	2	0.38	178
7.4	0.27	180	0.064	-11	3.06	-16	0.33	159
7.5	0.33	148	0.066	-28	3.00	-32	0.28	135
7.6	0.38	126	0.062	-43	2.90	-47	0.24	114
7.7	0.46	109	0.059	-58	2.66	-59	0.22	93

MGFC36V7785



S PARAMETERS ($T_a = 25^\circ\text{C}$, $V_{DS} = 10\text{V}$, $I_{DS} = 1.2\text{A}$)

f (GHz)	S Parameters (TYP.)							
	S ₁₁		S ₁₂		S ₂₁		S ₂₂	
	Magn.	Angle (deg.)	Magn.	Angle (deg.)	Magn.	Angle (deg.)	Magn.	Angle (deg.)
7.7	0.43	-65	0.066	30	2.51	17	0.48	-170
7.8	0.36	-80	0.068	14	2.53	5	0.44	-180
7.9	0.27	-103	0.070	-6	2.54	-15	0.41	165
8.0	0.21	-120	0.073	-21	2.62	-30	0.36	155
8.1	0.20	-159	0.076	-34	2.69	-43	0.33	140
8.2	0.18	170	0.076	-53	2.75	-57	0.27	125
8.3	0.24	126	0.080	-70	2.77	-71	0.21	107
8.4	0.30	101	0.076	-88	2.68	-86	0.16	81
8.5	0.37	80	0.076	-104	2.51	-100	0.13	50



ORDERING INFORMATION

Part Number	Grade	Tested at	P _{1dB} * (TYP)	IM ₃ * (MAX)
MGFC36V3742-01	Industrial	3.7 – 4.2 GHz	36 dBm	—
MGFC36V3742-51	Industrial	3.7 – 4.2 GHz	36 dBm	-42 dBc
MGFC36V4450-01	Industrial	4.4 – 5.0 GHz	36 dBm	—
MGFC36V4450-51	Industrial	4.4 – 5.0 GHz	36 dBm	-42 dBc
MGFC36V5258-01	Industrial	5.2 – 5.8GHz	36 dBm	—
MGFC36V5258-51	Industrial	5.2 – 5.8GHz	36 dBm	-42 dBc
MGFC36V5964-01	Industrial	5.9 – 6.4 GHz	36 dBm	—
MGFC36V5964-51	Industrial	5.9 – 6.4 GHz	36 dBm	-42 dBc
MGFC36V6471-01	Industrial	6.4 – 7.1 GHz	36 dBm	—
MGFC36V6471-51	Industrial	6.4 – 7.1 GHz	36 dBm	-42 dBc
MGFC36V7177-01	Industrial	7.1 – 7.7 GHz	36 dBm	—
MGFC36V7177-51	Industrial	7.1 – 7.7 GHz	36 dBm	-42 dBc
MGFC36V7785-01	Industrial	7.7 – 8.5 GHz	36 dBm	—
MGFC36V7785-51	Industrial	7.7 – 8.5 GHz	36 dBm	-42 dBc

*Test condition specified in 'Electrical Characteristics' section.